## NSN 5962-01-231-4703

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.840 inches	
Body Width:	
0.310 inches	
Body Height:	
0.185 inches	
Maximum Power D	issipation Rating:
794.0 milliwatts	
Operating Tempura	ature Range:
-55.0/+125.0 degree	s celsius
Storage Tempuratu	ire Range:
-65.0/+150.0 degree	s celsius
Features Provided:	
Monolithic and bipol	ar and programmable
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patter	n:
10 input	
Case Outline Sourc	ce And Designator:
D-2 mil-m-38510	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	d Type Per Characteristic:
-0.5 volts power sou	urce and 7.0 volts power source
Memory Device Ty	pe:
Prom	
Test Data Docume	nt:
96906-mil-std-883 s	tandard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	